

Exceptional properties of Disordered materials for novel applications

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The fabrication and characterization of disordered materials has recently witnessed an outstanding progress leading to materials with unprecedented properties. In particular, the possibility to synthesize wafer-scale two-dimensional amorphous carbon monolayers, structurally dominated by sp² hybridization, has been demonstrated. This achievement has initiated a new platform of low-dimensional materials allowing to explore alternative forms of membranes with enhanced chemical reactivity which could be employed for coating [1,2].

The excellent physical properties of the mentioned materials derive from the nature and degree of their disorder which, controlled at the fabrication level, represents the key ingredient to tune their physical/chemical properties for specific target applications. In this respect, new fabrication strategies to modify the degree of disorder and a systematic theoretical characterization of the impact of the material structural quality on the ultimate performance is urgent. Even more importantly, the search for new disordered materials for novel applications appears as an extremely promising way.

In this talk we present a systematic analysis of the structural and vibrational properties of amorphous carbon monolayers as a function of the structural quality of the material, showing how disorder results in a tunable thermal conductivity varying by more than one order of magnitude [3].

Finally, we present the results of the newly demonstrated synthesis of a thin film of amorphous Boron Nitride showing extremely low dielectric characteristics: high breakdown voltage and likely superior metal barrier properties [4]. The fabricated material aims at replacing current interconnect insulators in the next-generation of electronic circuits. We discuss the experimental setup and present the results of our calculations which have contributed to the understanding of the structural morphology of the amorphous material as well as explaining the superior dielectric performances.

REFERENCES

- [1] Joo, W.-J. et al., *Sci. Adv.* **3**, e1601821 (2017).
- [2] Toh, Chee-Tat, et al., *Nature* **577**:7789 (2020), 199-203
- [3] Antidormi, A. *et al* (submitted to 2D Materials)
- [4] Hong S. et al, *Nature* **582** (7813): 511 - 514. 2020

FIGURES

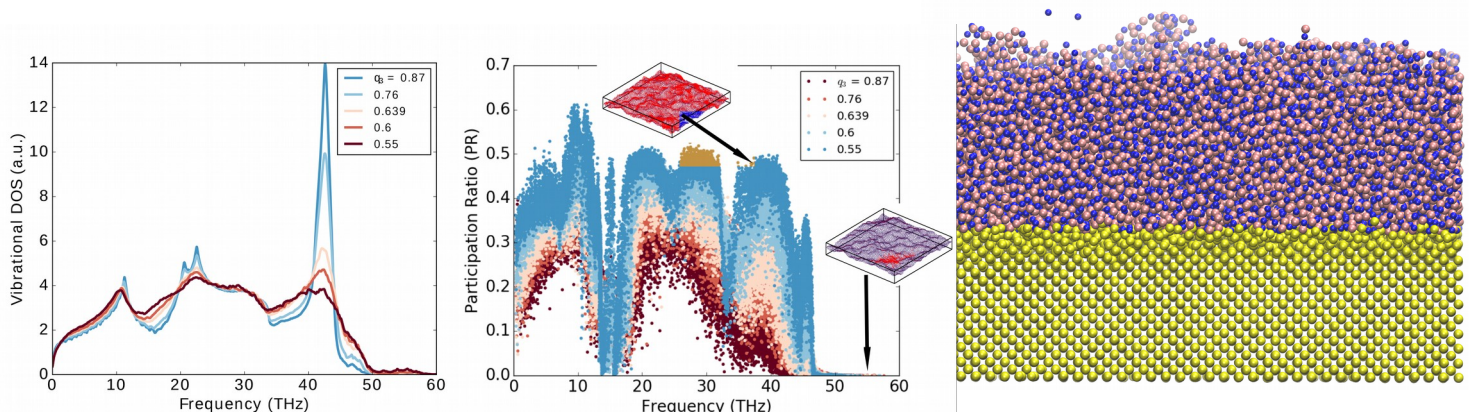


Figure 1: (Left) Vibrational DOS of Amorphous Graphene for different degrees of amorphousness. (Right) Participation Ratio of the samples and atomic displacements (insets)

Figure 2. Atomistic sample of Amorphous Boron Nitride.